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**Yu et al.**

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(54) **DATA WRITING METHOD FOR A FLASH MEMORY, AND CONTROLLER AND STORAGE SYSTEM USING THE SAME**

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*G11C 29/00* (2006.01)

(52) **U.S. Cl.**
USPC ..... **714/773**

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See application file for complete search history.

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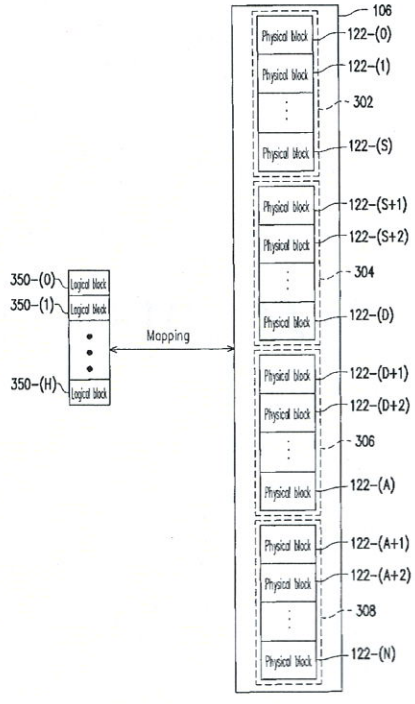
(74) *Attorney, Agent, or Firm* — J.C. Patents

(57) **ABSTRACT**

A data writing method for writing data from a host system into a flash memory chip is provided, and the flash memory chip has a plurality of physical blocks. The method includes receiving a host writing command and write data thereof, and executing the host writing command. The method also includes giving a data program command for writing the write data into one of the physical blocks of the flash memory chip, and giving a command for determining whether data stored in the physical block has any error bit. Accordingly, the method can effectively ensure the correctness of data to be written into the flash memory chip.

**13 Claims, 9 Drawing Sheets**



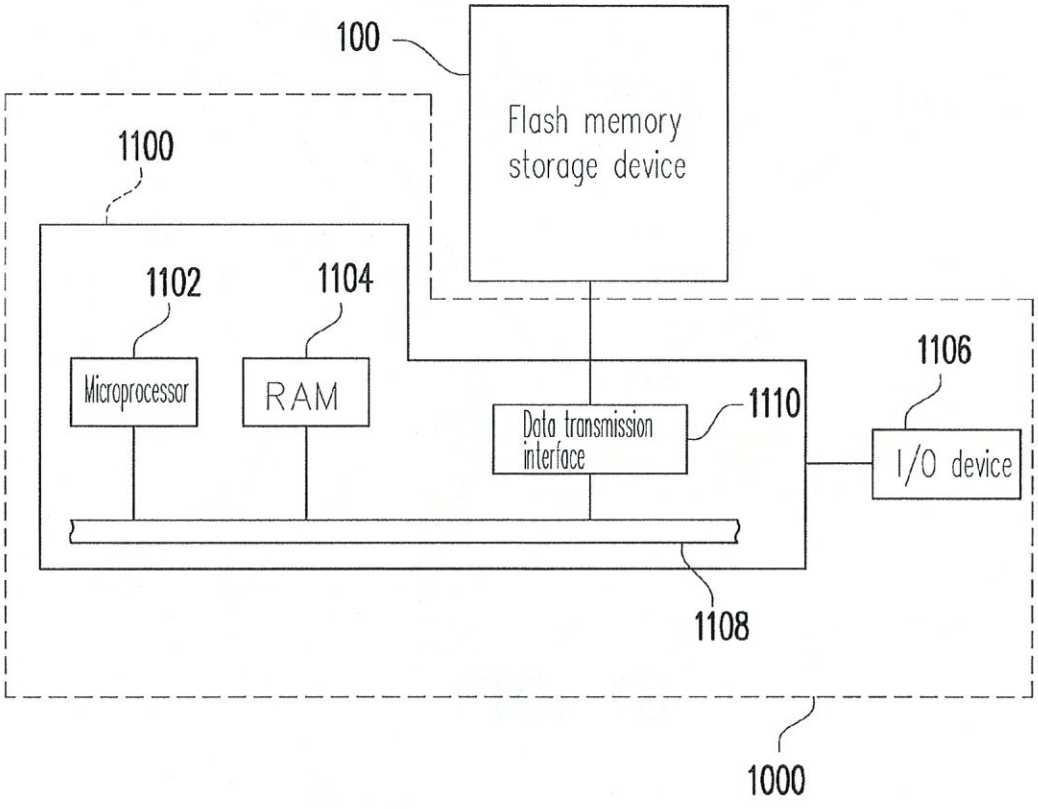

100
Flash memory storage device
1100
1102
1104
Microprocessor
RAM
Data transmission interface
1110
1106
I/O device
1108
1000

FIG. 1A

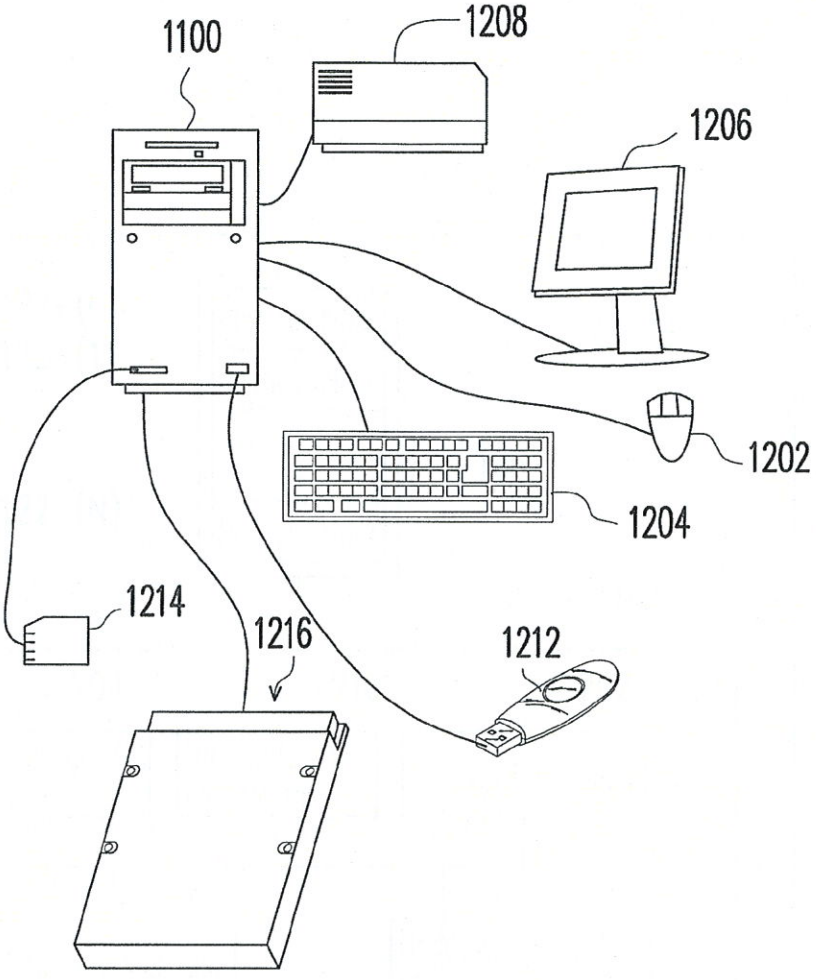

1100
1208
1206
1202
1204
1214
1216
1212

FIG. 1B

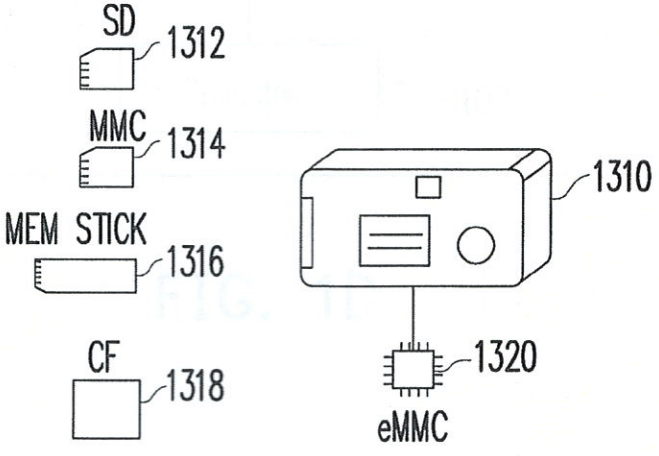

SD
1312
MMC
1314
MEM STICK
1316
CF
1318
1310
1320
eMMC

FIG. 1C

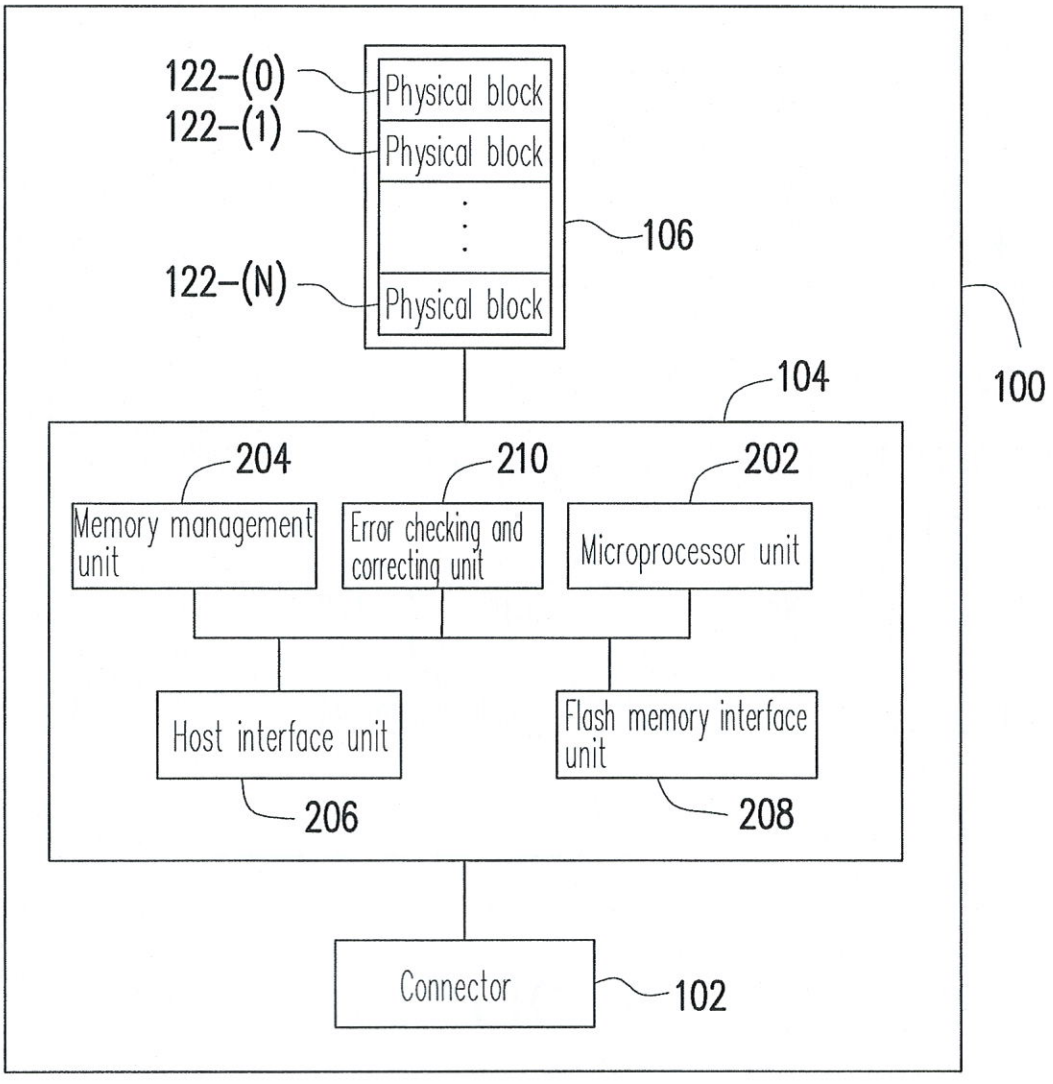

122-(0)
122-(1)
122-(N)
Physical block
Physical block
Physical block
106
100
104
204
210
202
Memory management unit
Error checking and correcting unit
Microprocessor unit
Host interface unit
Flash memory interface unit
206
208
Connector
102

FIG. 1D

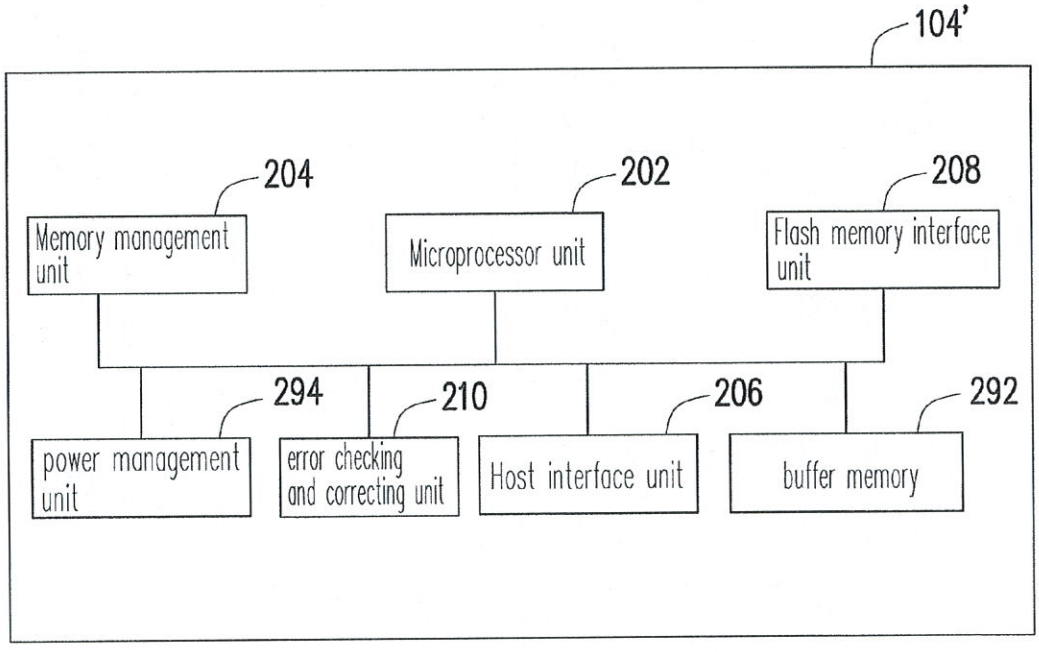

104'
204
Memory management unit
202
Microprocessor unit
208
Flash memory interface unit
294
power management unit
210
error checking and correcting unit
206
Host interface unit
292
buffer memory

FIG. 2

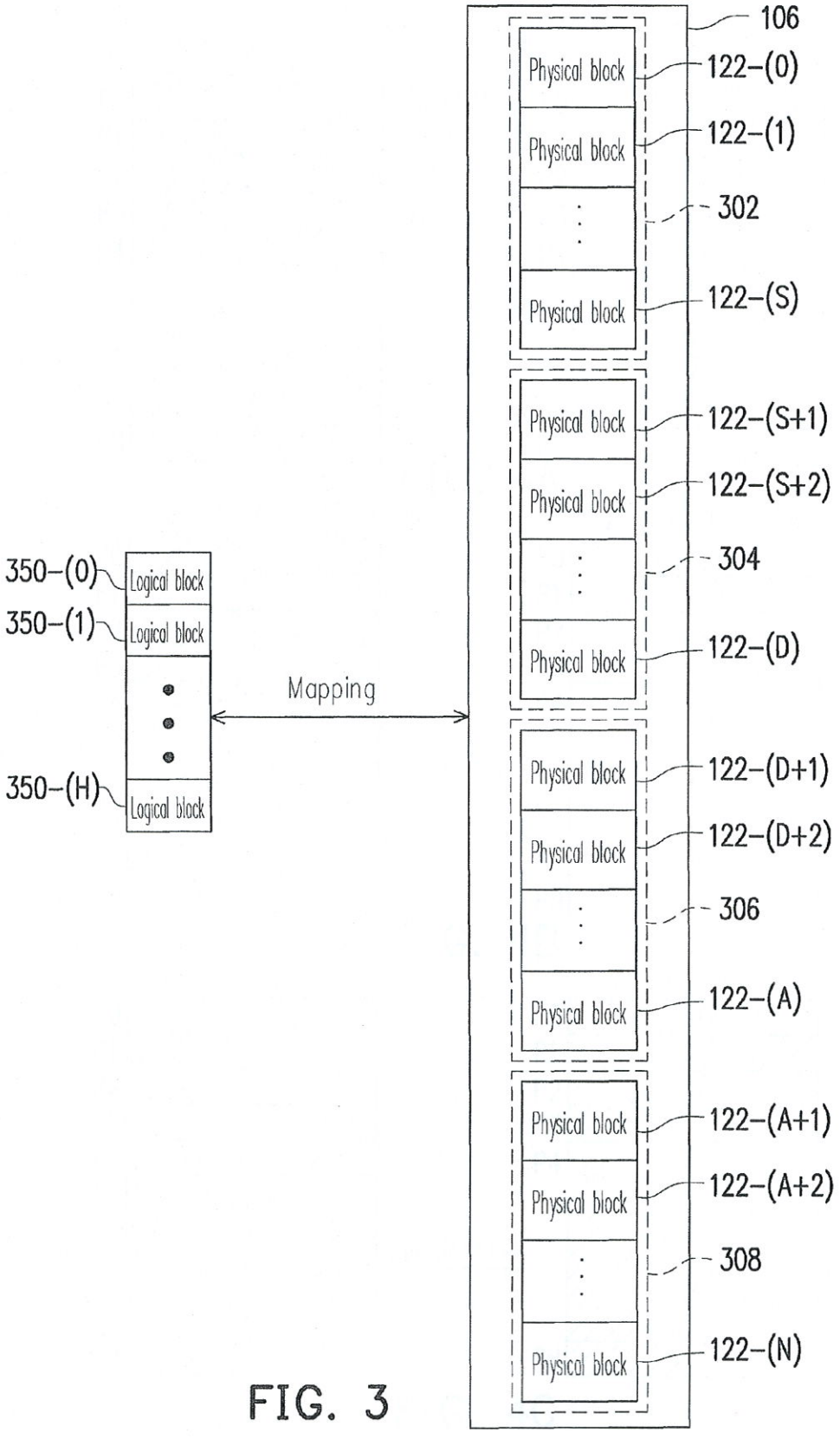

106
Physical block
122-(0)
Physical block
122-(1)
302
Physical block
122-(S)
Physical block
122-(S+1)
Physical block
122-(S+2)
304
Physical block
122-(D)
350-(0)
Logical block
350-(1)
Logical block
Mapping
350-(H)
Logical block
Physical block
122-(D+1)
Physical block
122-(D+2)
306
Physical block
122-(A)
Physical block
122-(A+1)
Physical block
122-(A+2)
308
Physical block
122-(N)

FIG. 3

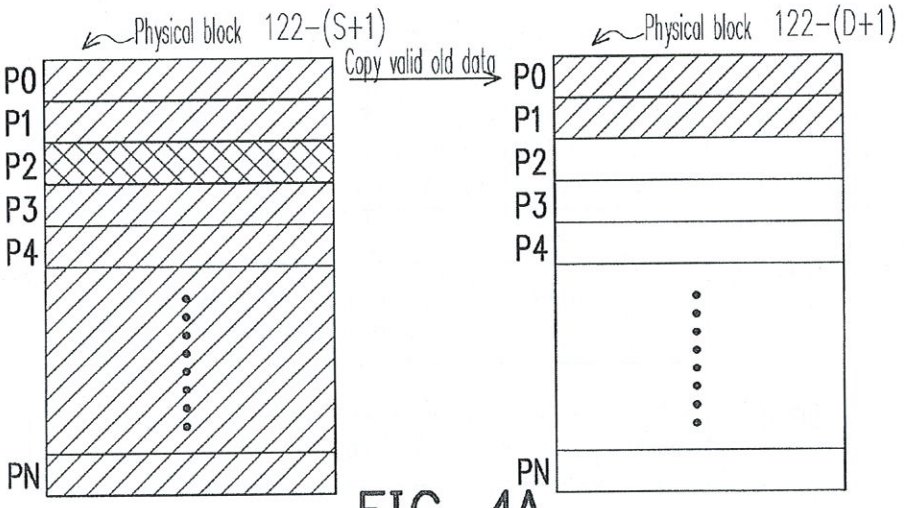



FIG. 4A

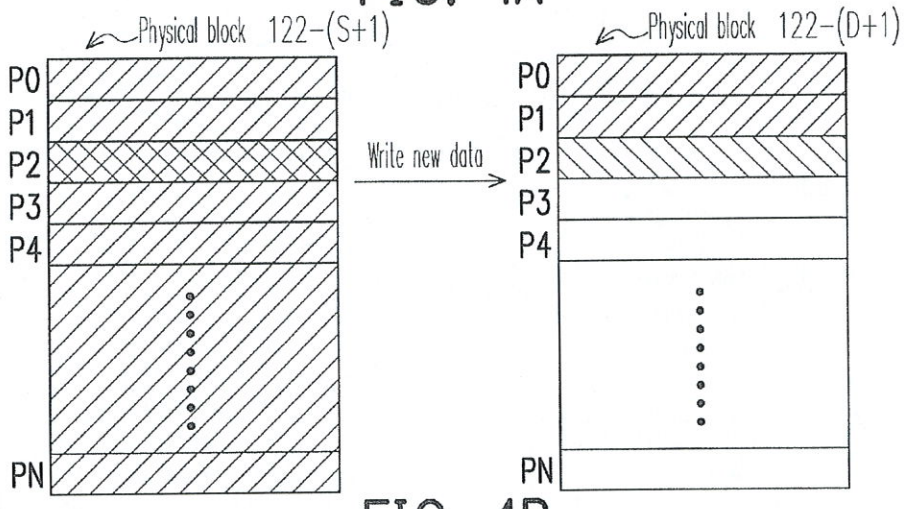



FIG. 4B

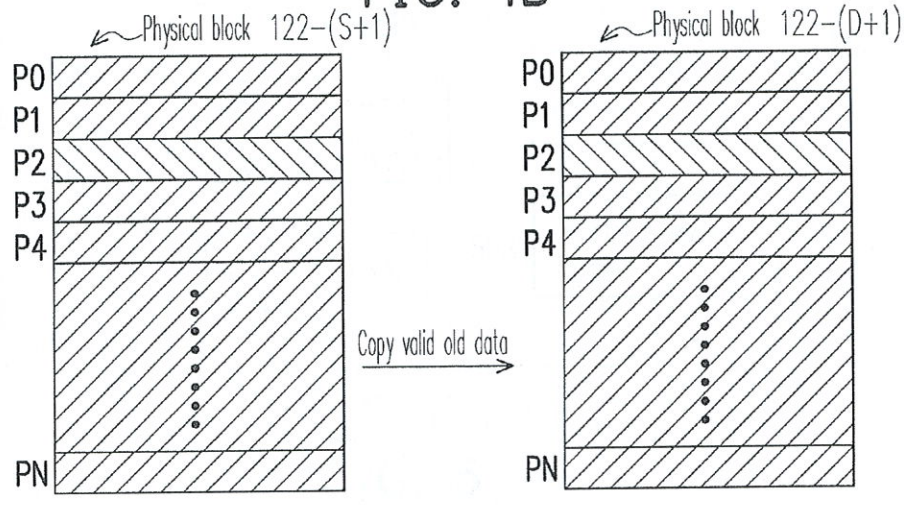



FIG. 4C

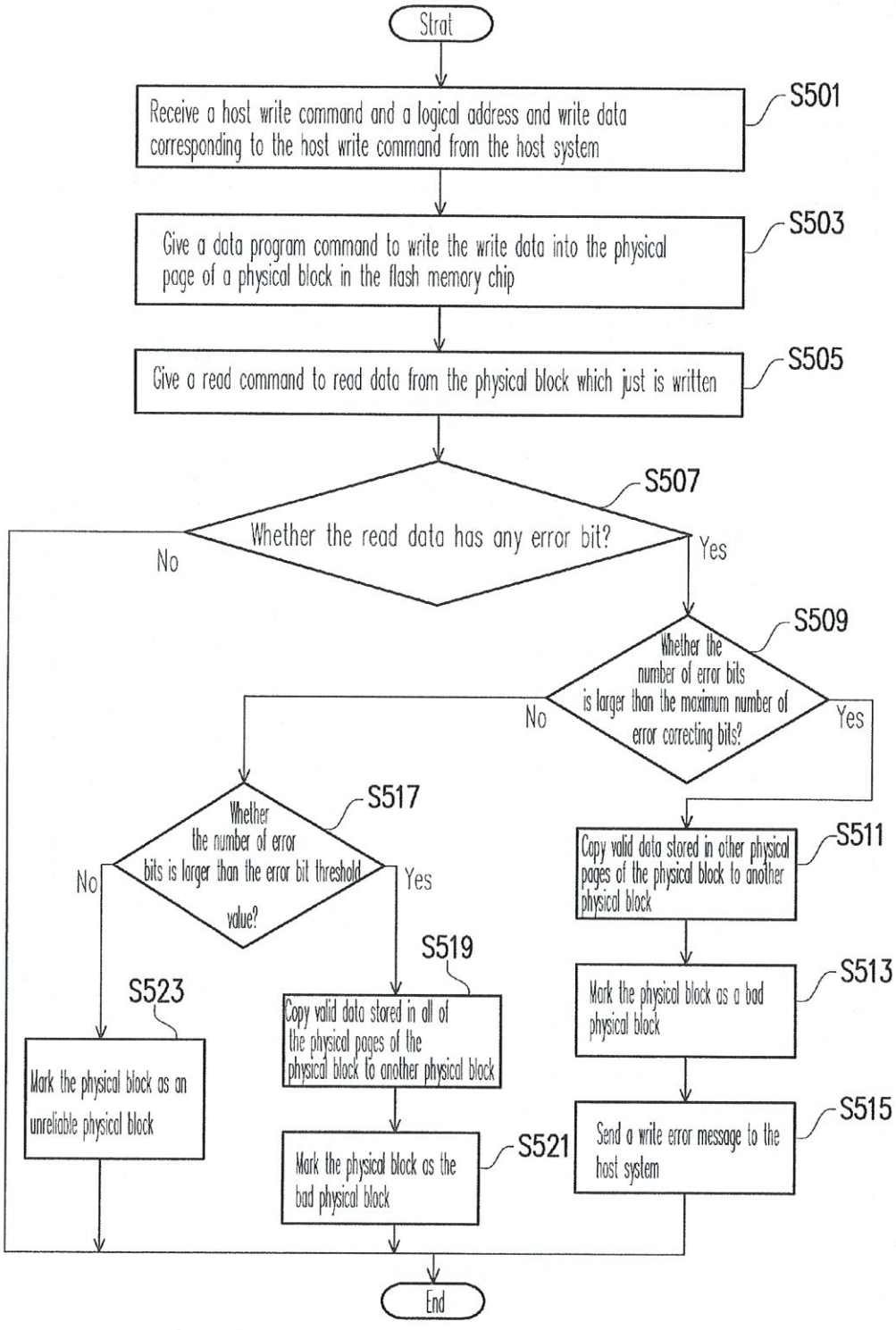

Strat
Receive a host write command and a logical address and write data corresponding to the host write command from the host system
S501
Give a data program command to write the write data into the physical page of a physical block in the flash memory chip
S503
Give a read command to read data from the physical block which just is written
S505
Whether the read data has any error bit?
S507
No
Yes
Whether the number of error bits is larger than the maximum number of error correcting bits?
S509
No
Yes
Whether the number of error bits is larger than the error bit threshold value?
S517
No
Yes
Copy valid data stored in other physical pages of the physical block to another physical block
S511
Mark the physical block as a bad physical block
S513
Send a write error message to the host system
S515
Copy valid data stored in all of the physical pages of the physical block to another physical block
S519
Mark the physical block as the bad physical block
S521
Mark the physical block as an unreliable physical block
S523
End

FIG. 5

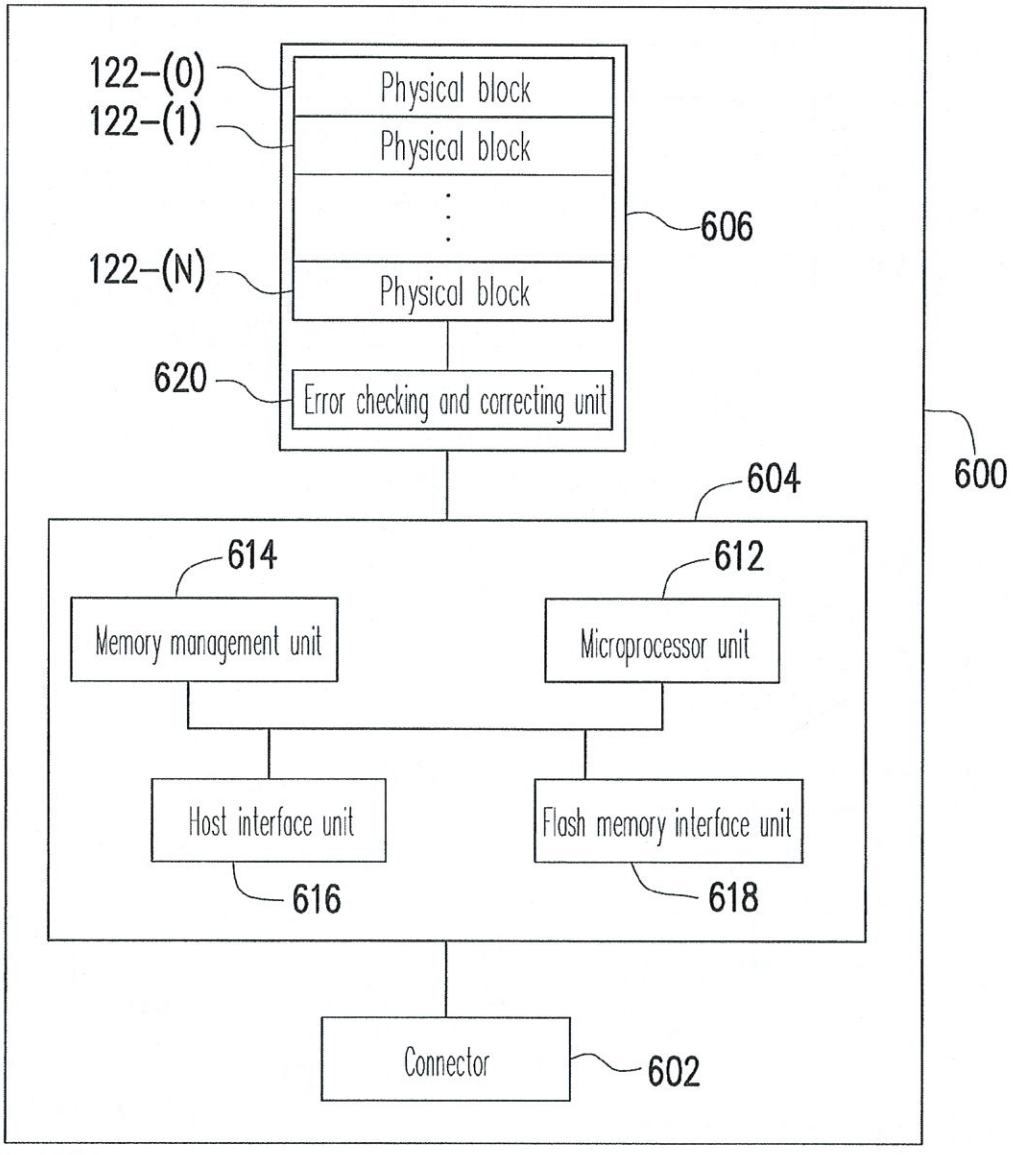

122-(0)
122-(1)
122-(N)
Physical block
Physical block
Physical block
606
620
Error checking and correcting unit
600
604
614
612
Memory management unit
Microprocessor unit
Host interface unit
Flash memory interface unit
616
618
Connector
602

FIG. 6

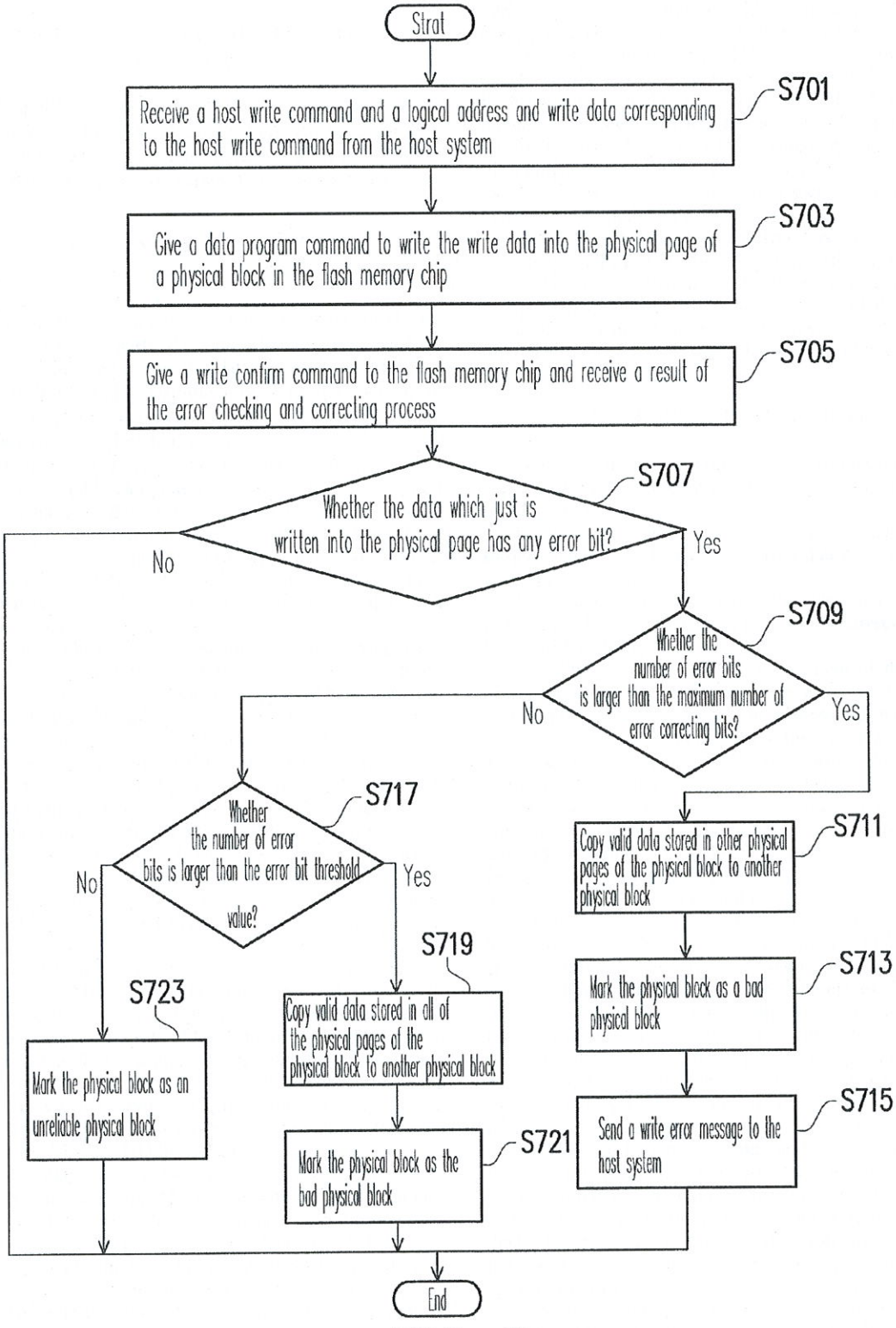

Strat
Receive a host write command and a logical address and write data corresponding to the host write command from the host system
S701
Give a data program command to write the write data into the physical page of a physical block in the flash memory chip
S703
Give a write confirm command to the flash memory chip and receive a result of the error checking and correcting process
S705
Whether the data which just is written into the physical page has any error bit?
S707
No
Yes
Whether the number of error bits is larger than the maximum number of error correcting bits?
S709
No
Yes
Whether the number of error bits is larger than the error bit threshold value?
S717
No
Yes
Copy valid data stored in other physical pages of the physical block to another physical block
S711
Mark the physical block as a bad physical block
S713
Send a write error message to the host system
S715
Copy valid data stored in all of the physical pages of the physical block to another physical block
S719
Mark the physical block as the bad physical block
S721
Mark the physical block as an unreliable physical block
S723
End

FIG. 7

# DATA WRITING METHOD FOR A FLASH MEMORY, AND CONTROLLER AND STORAGE SYSTEM USING THE SAME

## CROSS-REFERENCE TO RELATED APPLICATION

This application claims the priority benefit of Taiwan application serial no. 98134508, filed on Oct. 12, 2009. The entirety of the above-mentioned patent application is hereby incorporated by reference herein and made a part of this specification.

## BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention relates to a data writing method for a flash memory and particularly to a data writing method capable of effectively ensure that data is correctly written into a flash memory, and a flash memory controller and a flash memory storage system using the same.

2. Description of Related Art

Flash memory is the most adaptable memories to be applied in portable electronic products which are supplied power by batteries due to its data non-volatility, low power consumption, small volume, and non-mechanical structure. For example, a solid state drive (SSD) is a storage device that uses a NAND flash memory as its storage medium, and which has been broadly used in notebook computes as the main storage device.

A flash memory of a flash memory storage device has a plurality of physical blocks, and each physical block has a plurality of physical pages, wherein data must be written into a physical block according to the sequence of the physical pages in the physical block. Additionally, a flash memory may be classified into two types of NAND flash memory, a Single Level Cell (SLC) NAND flash memory and a Multi Level Cell (MLC) NAND flash memory, according to the number of bits that each memory cell thereof is capable of storing. In the SLC NAND flash memory, because an electric charge in one memory cell is only identified using one level, whether the bit stored in one memory cell represents '1' or '0' is thereby identified. Therefore, each memory cell only can store one bit of data.

Along with the improvement of flash memory manufacture processes, the MLC NAND flash memory has developed. To be specific, an electric charge in one memory cell can be identified using a plurality of levels in the MLC NAND flash memory. Therefore, one memory cell may store multiple bits of data in the MLC NAND flash memory. Accordingly, for the same number of memory cells, the number of pages in an MLC NAND flash memory is a multiple of the number of pages in an SLC NAND flash memory.

In particular, because one memory cell may stores multi-bits of data in the MLC NAND flash memory, the program for the physical blocks of the MLC NAND flash memory will include a plurality of phases. Taking a 2 level cell NAND flash memory as an example, the physical blocks thereof are programmed in a first phase and a second phase. The first phase is the programming of a lower page, and the physical property of the programming of the lower page is similar to the physical property of the programming of the SLC NAND flash memory. After the first phase is completed, the programming of an upper page may be executed (i.e. the second phase), wherein the speed of programming the lower page is faster than that of programming the upper page. Similarly, in an 8 level cell or a 16 level cell, each memory cell contains more pages and accordingly is programmed in more phases.



In the MLC NAND flash memory the programming of the upper page may be coupling with the programming of the lower page, therefore the reliability of the MLC NAND flash memory is lower than the SLC NAND flash memory. That is, the probability of occurring writing errors in the MLC NAND flash memory is higher than that in the SLC NAND flash memory. In particular, when one memory cell can store more bits of data in the MLC NAND flash memory, the probability of writing errors becomes higher. Thereof, how to ensure that data is correctly written into a flash memory is one of the major subjects in the industry.

Nothing herein should be construed as an admission of knowledge in the prior art of any portion of the present invention. Furthermore, citation or identification of any document in this application is not an admission that such document is available as prior art to the present invention, or that any reference forms a part of the common general knowledge in the art.

## SUMMARY OF THE INVENTION

The present invention is directed to a data writing method capable of effectively ensuring that data is correctly written into a flash memory.

The present invention is directed to a flash memory controller capable of effectively ensuring that data is correctly written into a flash memory.

The present invention is directed to a flash memory system capable of effectively ensuring that data is correctly written into a flash memory.

According to an exemplary embodiment of the present invention, a data writing method for writing data from a host system into a flash memory chip is provided, wherein the flash memory chip includes a plurality of physical blocks. The data writing method includes configuring a flash memory controller; receiving a host write command and write data corresponding to the host write command from the host system; and executing the host write command by the flash memory controller. The data writing method also includes giving a data program command to the flash memory chip to write the write data into one of the physical blocks and giving a command to the flash memory chip to determine whether at least a portion of data stored in the physical block has any error bit during the execution of the host write command.

According to an exemplary embodiment of the present invention, a flash memory controller for writing data from a host system into a flash memory chip is provided, wherein the flash memory chip includes a plurality of physical blocks. The flash memory controller includes a microprocessor unit, a flash memory interface unit, a host interface unit, and a memory management unit. The flash memory interface unit is coupled to the microprocessor unit and configured to couple to the flash memory chip. The host interface unit is coupled to the microprocessor unit and receives a host write command and write data corresponding to the host write command from the host system. The memory management unit is coupled to the microprocessor unit and gives a data program command to the flash memory chip to write the write data into one of the physical blocks during the execution of the host write command. Additionally, the memory management unit gives a command to the flash memory chip to determine whether at least a portion of data stored in the physical block has any error bit during the execution of the host write command.

According to an exemplary embodiment of the present invention, a flash memory storage system including a connec-

tor, a flash memory chip, and a flash memory controller is provided. The flash memory chip has a plurality of physical blocks. The connector is configured to couple to a host system and receives a host write command and write data corresponding to the host write command from the host system. The flash memory controller is coupled to the flash memory chip and the connector, and gives a data program command to the flash memory chip to write the write data into one of the physical blocks during the execution of the host write command. Additionally, the flash memory controller gives a command to the flash memory chip to determine whether at least a portion of data stored in the physical block has any error bit during the execution of the host write command.

As described above, the data writing method provided by the present invention determines whether data written into a flash memory has any error bits during the execution of the host write command, thereby the correctness of the data written into the flash memory can effectively be ensured.

In order to make the aforementioned and other features and advantages of the invention more comprehensible, embodiments accompanying figures are described in detail below.

It should be understood, however, that this Summary may not contain all of the aspects and embodiments of the present invention, is not meant to be limiting or restrictive in any manner, and that the invention as disclosed herein is and will be understood by those of ordinary skill in the art to encompass obvious improvements and modifications thereto.

## BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings are included to provide a further understanding of the invention, and are incorporated in and constitute a part of this specification. The drawings illustrate embodiments of the invention and, together with the description, serve to explain the principles of the invention.

FIG. **1**A is a schematic block diagram of a host system using a flash memory storage device according to a first exemplary embodiment of the present invention.

FIG. **1**B is a diagram of a computer, an input/output device, and a flash memory storage device according to an exemplary embodiment of the present invention.

FIG. **1**C is a schematic diagram of a host system and a flash memory storage device according to another exemplary embodiment of the present invention.

FIG. **1**D is a schematic block diagram of the flash memory storage device in FIG. **1**A.

FIG. **2** is a schematic block diagram of a flash memory controller according to another exemplary embodiment of the present invention.

FIG. **3** is a schematic block diagram illustrating a flash memory chip according to the first exemplary embodiment of the present invention.

FIGS. **4**A~**4**C are schematic diagrams illustrating operations of physical blocks according to the first exemplary embodiment of the present invention.

FIG. **5** is a flowchart illustrating a data writing method according to the first embodiment of the present invention.

FIG. **6** is a schematic block diagram illustrating a flash memory storage system according to a second exemplary embodiment of the present invention.

FIG. **7** is a flowchart illustrating a data writing method according to the second exemplary embodiment of the present invention.

## DESCRIPTION OF EMBODIMENTS

A flash memory storage device usually includes a flash memory chip and a controller (also referred to as a control circuit). The flash memory storage device is usually used together with a host system so that the host system can write data into or read data from the flash memory storage device. Besides, a flash memory storage device may also include an embedded flash memory and a software that can be executed by a host system and act as a controller of the embedded flash memory.

Embodiments of the present invention may comprise any one or more of the novel features described herein, including in the Detailed Description, and/or shown in the drawings. As used herein, "at least one", "one or more", and "and/or" are open-ended expressions that are both conjunctive and disjunctive in operation. For example, each of the expressions "at least on of A, B and C", "at least one of A, B, or C", "one or more of A, B, and C", "one or more of A, B, or C" and "A, B, and/or C" means A alone, B alone, C alone, A and B together, A and C together, B and C together, or A, B and C together.

It is to be noted that the term "a" or "an" entity refers to one or more of that entity. As such, the terms "a" (or "an"), "one or more" and "at least one" can be used interchangeably herein.

### First Exemplary Embodiment

FIG. **1**A is a schematic block diagram of a host system using a flash memory storage device according to a first exemplary embodiment of the present invention.

Referring to FIG. **1**A, a host system **1000** includes a computer **1100** and an input/output (I/O) device **1106**. The computer **1100** includes a microprocessor **1102**, a random access memory (RAM) **1104**, a system bus **1108**, and a data transmission interface **1110**. For example, the I/O device **1106** includes a mouse **1202**, a keyboard **1204**, a display **1206** and a printer **1208** as shown in FIG. **1**B. It should be understood that the devices illustrated in FIG. **1**B are not intended to limiting the I/O device **1106**, and the I/O device **1106** may further include other devices.

In the present embodiment, the flash memory storage device **100** is coupled to other devices of the host system **1000** through the data transmission interface **1110**. The host system **1000** can write data into or read data from the flash memory storage device **100** through the operations of the microprocessor **1102**, the RAM **1104**, and the I/O device **1106**. For example, the flash memory storage device **100** may be a flash drive **1212**, a memory card **1214**, or a solid state drive (SSD) **1216** as shown in FIG. **1**B.

Generally speaking, the host system **1000** may be any system for storing data. Even though the host system **1000** is described as a computer system in the present exemplary embodiment, in another exemplary embodiment of the present invention, the host system **1000** may be a digital camera, a video camera, a telecommunication device, an audio player, or a video player. For example, if the host system is a digital camera (video camera) **1310**, the flash memory storage device is then a SD card **1312**, a MMC card **1314**, a memory stick **1316**, a CF card **1318** or an embedded storage device **1320** (as shown in FIG. **1**C). The embedded storage device **1320** includes an embedded MMC (eMMC). It should be mentioned that the eMMC is directly coupled to a substrate of the host system.

FIG. **1**D is a schematic block diagram of the flash memory storage device **100** in FIG. **1**A.

Referring to FIG. **1**D, the flash memory storage device **100** includes a connector **102**, a flash memory controller **104**, and a flash memory chip **106**.

The connector **102** is coupled to the flash memory controller **104** and configured to couple to the host system **1000**. In the present embodiment, the connector **102** is a serial advanced technology attachment (SATA) connector. However, the present invention is not limited thereto, and the connector **102** may also be a Parallel Advanced Technology Attachment (PATA) connector, a universal serial bus (USB) connector, an Institute of Electrical and Electronic Engineers (IEEE) 1394 connector, a peripheral component interconnect (PCI) express connector, a secure digital (SD) connector, a memory stick (MS) connector, a multi media card (MMC) connector, a compact flash (CF) connector, an integrated device electronics (IDE) connector, or other suitable connector.

The flash memory controller **104** executes a plurality of logic gates or control commands which are implemented in a hardware form or in a firmware form, so as to perform operations of writing, reading or erasing data in the flash memory chip **106** according to the commands of the host system **1000**. The flash memory controller **104** includes a microprocessor unit **202**, a memory management unit **204**, a host interface unit **206**, a flash memory interface unit **208** and an error checking and correcting unit **210**.

The microprocessor unit **202** is the main control unit of the flash memory controller **104**, and cooperates with the memory management unit **204**, the host interface unit **206**, the flash memory interface unit **208** and the error checking and correcting unit **210** to carry out various operations of the flash memory storage device **100**.

The memory management unit **204** is coupled to the microprocessor unit **202**, and executes a data writing mechanism and a block management mechanism according to the present exemplary embodiment. Below, the operation of the memory management unit **204** will be described in detail with reference to accompanying drawings.

In the present exemplary embodiment, the memory management unit **204** is implemented in the flash memory controller **104** as a firmware form. For example, the memory management unit **204** including a plurality of control instructions is burned into a program memory (for example, a read only memory (ROM)), and the program memory is embedded into the flash memory controller **104**. When the flash memory storage device **100** is in operation, the control instructions of the memory management unit **204** are executed by the microprocessor unit **202** to accomplish the block management mechanism and the data writing mechanism according to the present embodiment.

In another exemplary embodiment of the present invention, the control instructions of the memory management unit **204** may also be stored in a specific area (for example, the system area in a flash memory exclusively used for storing system data) of the flash memory chip **106** as program codes. Similarly, when the flash memory storage device **100** is in operation, the program instructions of the memory management unit **204** are executed by the microprocessor unit **202**. In addition, in yet another exemplary embodiment of the present invention, the memory management unit **204** may also be implemented in the flash memory controller **104** in a hardware form.

The host interface unit **206** is coupled to the microprocessor unit **202** and configured to receive and identify commands and data received from the host system **1000**. Namely, the commands and data sent by the host system **1000** are passed to the microprocessor unit **202** through the host interface unit **206**. In the present exemplary embodiment, the host interface unit **206** is a SATA interface corresponding to the connector **102**. However, it is to be understood that the present invention is not limited thereto, and the host interface unit **210** may also be a PATA interface, a USB interface, an IEEE 1394 interface, a PCI Express interface, a SD interface, a MS interface, a MMC interface, a CF interface, an IDE interface, or other suitable types of interfaces for data transmission.

The flash memory interface unit **208** is coupled to the microprocessor unit **202** and configured to access the flash memory chip **106**. Namely, data to be written into the flash memory chip **106** is converted by the flash memory interface unit **208** into a format acceptable to the flash memory chip **106**.

The error checking and correcting unit **210** is coupled to the microprocessor unit **202** and configured to perform an error checking and correcting process to ensure the correctness of data. To be specific, when the memory management unit **204** receives a host write command from the host system **1000**, the error checking and correcting unit **210** generates an error checking and correcting code (ECC code) corresponding to write date of the host write command, and the memory management unit **204** writes the write data and the ECC code into the flash memory chip **106**. And, when the memory management unit **204** reads data from the flash memory chip **106**, the memory management unit **204** simultaneously reads the ECC code corresponding the read data, and the error checking and correcting unit **210** performs the error checking and correcting process to the read data based on the ECC code corresponding to the read data. In the present exemplary embodiment, the maximum number of error bits which can be corrected by the error checking and correcting unit **210** is 26. And, the maximum number of error bits which can be corrected by the error checking and correcting unit is referred as "the maximum number of error correcting bits" hereafter. Namely, in a case where the number of error bits in data is not larger than 26, the error checking and correcting unit **210** is capable of detecting the error bits and correcting the data. It should be noted that the present invention is not limited thereto and the maximum number of error correcting bits of the error checking and correcting unit may be any suitable value, such as 4, 16 or 64.

In another exemplary embodiment of the present invention, the flash memory controller may further include some general function modules. FIG. **2** is a schematic block diagram of a flash memory controller according to another exemplary embodiment of the present invention.

Referring to FIG. **2**, besides the microprocessor unit **202**, the memory management unit **204**, the host interface unit **206**, the flash memory interface unit **208** and the error checking and correcting unit **210**, a flash memory controller **104'** further includes buffer memory **292** and a power management unit **294**.

The buffer memory **292** is coupled to the microprocessor unit **202** and configured to temporarily store data and commands from the host system **1000** or data from the flash memory chip **106**.

The power management unit **294** is coupled to the microprocessor unit **202** and configured to control the power of the flash memory storage device **100**.

The flash memory chip **106** is coupled to the flash memory controller **104** for storing data. The flash memory chip **106** has a plurality of physical blocks **122**-(**0**)~**122**-(N). Each of the physical blocks **122**-(**0**)~**122**-(N) is the smallest erasing unit. That is to say, each of the physical blocks has a minimum number of memory cells for being erased altogether. Each physical block has several pages. In the present exemplary embodiment, each of the pages is the smallest programming unit. In other words, each page is the smallest unit for writing data or reading data. Each of the pages usually includes a user

data area and a redundancy area. The data area is used to store user data, and the redundant area is used to store system data (for example, an error checking and correcting (ECC) Code). In the exemplary embodiment, the flash memory chip **106** is a multi-level cell (MLC) NAND flash memory chip. However, the present invention is not limited thereto, and in another embodiment of the present invention, the flash memory chip **106** may also be a single level cell (SLC) NAND flash memory.

FIG. **3** is a schematic block diagram illustrating a flash memory chip according to the first exemplary embodiment of the present invention and FIGS. **4**A-**4**C are schematic diagrams illustrating operations of physical blocks according to the first exemplary embodiment of the present invention.

Referring to FIG. **4**A~**4**C, because the memory cells of the flash memory chip **106** only be programmed from '1' to '0', data in a physical block has to be erased before the physical block is updated. However, since data is written into a flash memory in unit of pages and is erased from the same in unit of physical blocks, the physical blocks in the flash memory chip **106** are alternatively used for storing data.

To be specific, the memory management unit **204** logically groups the physical blocks into a system area **302**, a data area **304**, a spare area **306**, and a replacement area **308**.

The physical blocks **122**-(**0**)~**122**-(S) logically belonging to the system area **302** are configured to record system data, wherein the system data includes the manufacturer and model of the flash memory chip, the number of zones in flash memory chip, the number of physical blocks in each zone, and the number of pages in each physical block.

The physical blocks **122**-(S+1)~**122**-(D) logically belonging to the data area **304** stores the user data and are the physical blocks generally corresponding to the logical blocks accessed by the host **1000**. That is to say, the physical blocks of the data area are blocks which store valid data.

The physical blocks **122**-(D+1)~**122**-(A) logically belonging to the spare area **306** are configured to substitute the physical blocks in the data area **304**. Accordingly, the physical blocks in the spare area are either blank or available blocks (i.e., no data is recorded in these blocks or data recorded in these blocks is marked as invalid data). In other words, the physical blocks in the data area and the spare area are alternatively configured to store data written into the flash memory storage device **100** by the host system **1000**.

The physical blocks **122**-(A+1)~**122**-(N) logically belonging to the replacement area **308** are replacement physical blocks. For example, when the flash memory chip **106** is manufactured in the factory, 4% of the physical blocks thereof are reserved for replacement (i.e., the substitute physical units). Namely, when any physical block in the system area **302**, the data area **304**, and the spare area **306** is damaged, a physical block in the replacement area **308** is configured to replace the damaged physical block (i.e., the bad block). Thus, if there are still available physical blocks in the replacement area **308** and a physical block is damaged, the memory management unit **204** selects an available physical block from the replacement area **308** for replacing the damaged physical block. If there is no more available physical block in the replacement area **308** and a physical block is damaged, the flash memory storage device **100** is announced as being in a write-protect status and data cannot be written therein.

Because data from the host system **1000** is written into the flash memory storage device **100** in the alternative manner described above, the flash memory controller **104** provides logical blocks **350**-(**0**)~**350**-(H) to the host system **1000** for accessing data and maintains a logical address-physical address mapping table for recording the mapping relationships between the logical blocks **350**-(**0**)~**350**-(H) and the physical blocks **122**-(**0**)~**122**-(N).

For example, when the host system is about to store data into the logical block **350**-(**0**), the flash memory controller **104** gets to know that the logical block **350**-(**0**) is currently mapped to the physical block **122**-(S+1) logically belonging to the data area **304** according to the logical address-physical address mapping table. Thus, the memory management unit **204** updates the data in the physical block **122**-(S+1), and meanwhile, the flash memory controller **104** gets a physical block **122**-(D+1) from the spare area **306** to substitute the physical block **122**-(S+1) of the data area **304**. However, the memory management unit **204** does not instantly move all the valid data in the physical block **122**-(S+1) into the physical block **122**-(D+1) and erase the physical block **122**-(S+1) when the memory management unit **204** writes the new data into the physical block **122**-(D+1). To be specific, the memory management unit **204** copies the valid data (i.e., the pages P**0** and P**1**) to the physical block **122**-(D+1) before the page for writing the new data in the physical block **122**-(S+1) (as shown in FIG. **4**A) and writes the new data (i.e., the pages P**2** in the physical block **122**-(D+1)) into the physical block **122**-(D+1) (as shown in FIG. **4**B). By now, the flash memory controller **104** completes the data writing operation and responds to the host system **1000** that the write command has been executed. Because the valid data in the physical block **122**-(S+1) may become invalid during a next operation (for example, a write command), instantly moving all the valid data in the physical block **122**-(S+1) to the physical block **122**-(D+1) may become meaningless. In this case, an integration of the contents of the physical block **122**-(S+1) and the physical block **122**-(D+1) is a complete content of the mapping logic block **350**-(**0**). Here, at this time, the physical block **122**-(S+1) and the physical block **122**-(D+1) are referred to as mother-child blocks. The number of mother-child blocks is determined according to the size of a buffer memory in the flash memory controller **104**, and the action of temporarily maintaining such a mother-child relationship is referred to as opening mother-child blocks.

Thereafter, the flash memory controller **104** integrates the physical block **122**-(S+1) and the physical block **122**-(D+1) into a single physical block only when the contents of the two are to be actually combined, so that the efficiency of using physical blocks can be improved. The operation of integrating the physical blocks is also referred to as closing mother-child blocks.

For example, as shown in FIG. **4**C, when the host system **1000** transfers a write command to the flash memory controller **104** to store data into another logical block and the memory management unit **204** determines that the number of opening mother-child blocks has reached the upper limit of the system and accordingly needs to integrate the physical block **122**-(S+1) and the physical block **122**-(D+1), the memory management unit **204** copies the remaining valid data (i.e., the pages P**3**~PN) in the physical block **122**-(S+1) to the physical block **122**-(D+1), then erases the physical block **122**-(S+1) and links the physical block **122**-(S+1) to the spare area **306**. Meanwhile, the memory management unit **204** links the physical block **122**-(D+1) to the data area **304** and maps the logical block **350**-(**0**) to the physical block **122**-(D+1) in the logical address-physical address mapping table, so as to close the mother-child blocks.

In the present exemplary embodiment, when the host interface unit **206** receives a host write command and write data corresponding to the host write command from the host system **1000**, the memory management unit **204** gives a data program command to the flash memory chip **106** for writing

the write data from the host system **1000** into the physical blocks. To be specific, each of the logical blocks **350**-(**0**) ~**350**-(H) includes a plurality of logical pages, and each of the logical pages is composed of several logical addresses. Accordingly, when the host system **1000** accesses data at the logical addresses, the memory management unit **204** actually writes data into or read data from the physical page of the physical block mapped to the logical block that the accessed logical addresses belong to. In the exemplary embodiment, the memory management unit **204** transforms the logical addresses instructed in the host write command to a mapped logical block by using a logical operation formula, and gets the physical block mapped to the mapped logical block based on the logical address-physical address mapping table.

In particular, after the write data is written into the page of the physical block, the memory management unit **204** gives a read command to the flash memory chip **106** for reading data which just is written, and the error checking and correcting unit **210** performs the error checking and correcting process to the read data to determine whether an error occurs during the operation of writing the write data. For example, after the memory management unit **204** writes the write data into the physical page P**2** of the physical block **122**-(D+1) by giving the data program command, the memory management unit **204** gives the read command to read data stored in the physical page P**2** of the physical block **122**-(D+1), and the error checking and correcting unit **210** performs the error checking and correcting process to the read data to determine whether the read data has any error bit. And, when the read data has at least one error bit, the memory management unit **204** identifies that an error occurs during the operation of writing the write data and the data stored in the physical page P**2** of the physical block **122**-(D+1) is not correct. Namely, in the present exemplary embodiment, during the execution of a host write command, besides the operation of writing the write data into the flash memory chip **106**, the memory management unit **204** further reads the write data to verify whether the write data correctly is written. Here, "during the execution of the host write command" means a period which is from a time point of giving a host write command to the flash memory controller **104** by the host system **1000** to a time point of sending an acknowledgement message (i.e. a message which informs that the host write command is completed) to the host system **1000** by the flash memory controller **104**.

For example, during the execution of a host write command, if the error checking and correcting unit **210** determines the data read from the physical page P**2** of the physical block **122**-(D+1) has error bits and the number of error bits is larger than the maximum number of error correcting bits of the error checking and correcting unit **210** (i.e. the error checking and correcting unit **210** can not correct the error bits), memory management unit **204** moves valid data stored in other physical pages of the physical block **122**-(D+1) to another physical block (e.g. the physical block **122**-(D+2)) and marks the physical block **122**-(D+1) as a bad physical block. And, the memory management unit **204** sends a write error message to the host system **1000**. For example, the host system **1000** may re-send the host write command and the write data corresponding to the host write command according to the write error message.

Additionally, in a case where the error checking and correcting unit **210** determines the data read from the physical page P**2** of the physical block **122**-(D+1) has error bits, if the number of error bits is not larger than the maximum number of error correcting bits of the error checking and correcting unit **210** (i.e. the error checking and correcting unit **210** can correct the error bits), the memory management unit **204** determines whether the number of error bits is larger than an error bit threshold value. And, if the number of error bits is larger than the error bit threshold value, the memory management unit **204** moves valid data stored in all of the physical pages of the physical block **122**-(D+1) to another physical block (e.g. the physical block **122**-(D+2)) and marks the physical block **122**-(D+1) as the bad physical block. Here, the error bit threshold value may be any suitable value. To be specific, in the case where the number of error bits of the data is not larger than the maximum number of error correcting bits of the error checking and correcting unit **210**, when the number of error bits which occur in the data is larger than the error bit threshold value, the physical block stored the data is in a very unreliable status. Thus, the memory management unit **204** marks the physical block as the bad physical block. In the present exemplary embodiment, the error bit threshold value is set as 50% of the maximum number of error correcting bits of the error checking and correcting unit **210**.

Furthermore, in the case where the number of error bits of the data is not larger than the error bit threshold value, the memory management unit **204** marks the physical block **122**-(D+1) as an unreliable physical block. To be specific, the memory management unit **204** uses an unreliable physical block table for recording information related to the unreliable physical block. In particular, subsequently, when the memory management unit **204** performs write operations to store data in the alternative manner, the physical blocks recorded in the unreliable physical block table will not be considered to be used first. For example, the memory management unit **204** first uses the physical blocks of the replacement area **308** to store data. And, only when the bad physical blocks are too many and the write operations can not be performed to write data, the memory management unit uses the physical blocks recorded in the unreliable physical block table to write the data.

It should be mentioned that the memory management unit **204** reads data which just is written from a physical block to verify whether the data is written correctly when the memory management unit **204** performs the write operation to the physical block. However, the present invention is not limited thereto, in another exemplary embodiment of the present invention, the memory management unit **204** further read data stored in other physical pages of the written physical block to determine the status of the written physical block.

FIG. **5** is a flowchart illustrating a data writing method according to the first embodiment of the present invention.

Referring to FIG. **5**, in step S**501** the flash memory controller **104** receives a host write command and a logical address and write data corresponding to the host write command from the host system **1000**.

In step S**503**, the memory management unit **204** of the flash memory controller **104** uses a data program command to write the write data into the physical page of a physical block in the flash memory chip **106** (e.g. the physical page P**2** of the physical block **122**-(D+1)) based on the logical block that the logical address corresponding to the host write command belongs to.

After that, in step S**505**, memory management unit **204** gives a read command to read data from the physical block which just is written (e.g. the physical page P**2** of the physical block **122**-(D+1)), and in step S**507**, the error checking and correcting unit **210** performs the error checking and correcting process to the read data to determine whether the read data has any error bit.

If in the step S507 the error checking and correcting unit **210** determines that the read data does not have any error bit, the process shown in FIG. **5** is terminated.

If in the step S507 the error checking and correcting unit **210** determines that the read data has at least one error bit, in step S509 the memory management unit **204** determines whether the number of error bits is larger than the maximum number of error correcting bits of the error checking and correcting unit **210** based on the result of the error checking and correcting process. And, if the number of error bits is larger than the maximum number of error correcting bits, in step S511 the memory management unit **204** copies valid data stored in other physical pages of the physical block to another physical block (e.g. the physical block **122**-(D+2)) and in step S513 the memory management unit **204** marks the physical block (i.e. the physical block is written in step S503) as the bad physical block. Then, in the step S515 the memory management unit **204** sends a write error message to the host system **1000**, and the process shown in FIG. **5** is terminated.

If the number of error bits is not larger than the maximum number of error correcting bits, in step S517 the memory management unit **204** determines whether the number of error bits is larger than the error bit threshold value based on the result of the error checking and correcting process. If the number of error bits is larger than the error bit threshold value, in step S519 the memory management unit **204** copies valid data stored in all of the physical pages of the physical block to another physical block (e.g. the physical block **122**-(D+2)). And, in the step S521 the memory management unit **204** marks the physical block (i.e. the physical block is written in step S503) as the bad physical block, and the process shown in FIG. **5** is terminated.

If the number of error bits is not larger than the error bit threshold value, in step S523 the memory management unit **204** marks the physical block (i.e. the physical block is written in step S503) as the unreliable physical block, and the process shown in FIG. **5** is terminated. As described above, for example, in step S523 the memory management unit **204** uses the unreliable physical block table for recording information related to the physical block which is marked as the unreliable physical block.

It should be mentioned that in the exemplary embodiment, the memory management unit **204** reads data which just is written from a physical block and the error checking and correcting unit **210** performs the error checking and correcting process to determine whether the data is written correctly when the host write command is executed. However, the present invention is not limited thereto, in another exemplary embodiment of the present invention, the memory management unit **204** may compare the read data and the writing data from the host system **1000** bit by bit to determine whether the read data has any error bit and the number of error bits thereof.

## Second Exemplary Embodiment

FIG. **6** is a schematic block diagram illustrating a flash memory storage system according to a second exemplary embodiment of the present invention.

The flash memory storage device **600** is coupled to other devices of the host system **1000** through the data transmission interface **1110**. Data can be written into or read from the flash memory storage device **600** through the operations of the microprocessor **1102**, the RAM **1104**, and the I/O device **1106**. Similarly, the flash memory storage device **600** may be the flash drive **1212**, the memory card **1214**, or the solid state drive (SSD) **1216** as shown in FIG. **1**B, or the SD card **1312**, the MMC card **1314**, the memory stick **1316**, the CF card **1318** or the embedded storage device **1320** (as shown in FIG. **1**C). The embedded storage device **1320** includes an embedded MMC (eMMC). It should be mentioned that the eMMC is directly coupled to a substrate of the host system.

Referring to FIG. **6**, the flash memory storage device **600** includes a connector **602**, a flash memory controller **604**, and a flash memory chip **606**.

The connector **602** is coupled to the flash memory controller **604** and configured to connect to the host system **1000**. In the present embodiment, the connector **602** is a SATA connector. However, the present invention is not limited thereto, and the connector **602** can also be a PATA connector, a USB connector, an IEEE 1394 connector, a PCI Express connector, an MS connector, an MMC connector, an SD connector, a CF connector, an IDE connector, or other suitable connectors.

The flash memory controller **604** executes a plurality of logic gates or control commands which are implemented in a hardware form or in a firmware form, so as to perform operations of writing, reading or erasing data in the flash memory chip **606** according to the commands of the host system **1000**. The flash memory controller **604** includes a microprocessor unit **612**, a memory management unit **614**, a host interface unit **616** and a flash memory interface unit **618**. The structure and functionality of the microprocessor unit **612**, the host interface unit **616**, and the flash memory interface unit **618** essentially are similar to the structure and functionality of the microprocessor unit **202**, the host interface unit **206**, and the flash memory interface unit **208**, so they will not be repeated here.

The memory management unit **614** is coupled to the microprocessor unit **612**, and executes a data writing mechanism and a block management mechanism according to the present exemplary embodiment. Below, the operation of the memory management unit **614** will be described in detail with reference to accompanying drawings.

In the present exemplary embodiment, the memory management unit **614** is implemented in the flash memory controller **604** as a firmware form. For example, the memory management unit **614** including a plurality of control instructions is burned into a program memory (for example, a read only memory (ROM)), and the program memory is embedded into the flash memory controller **604**. When the flash memory storage device **600** is in operation, the control instructions of the memory management unit **614** are executed by the microprocessor unit **612** to accomplish the block management mechanism and the data writing mechanism according to the present embodiment.

In another exemplary embodiment of the present invention, the control instructions of the memory management unit **614** may also be stored in a specific area (for example, the system area in a flash memory exclusively used for storing system data) of the flash memory chip **606** as program codes. Similarly, when the flash memory storage device **600** is in operation, the program instructions of the memory management unit **614** are executed by the microprocessor unit **612**. In addition, in yet another exemplary embodiment of the present invention, the memory management unit **614** may also be implemented in the flash memory controller **104** in a hardware form.

The flash memory chip **606** is coupled to the flash memory controller **604** for storing data. The flash memory chip **606** is a MLC NAND flash memory chip and has a plurality of physical blocks **122**-(**0**)~**122**-(N) and an error checking and correcting unit **620**. The configuration and operation of the physical blocks in the second exemplary embodiment are identical to the ones in the first exemplary embodiment, a detailed description is omitted.

The error checking and correcting unit **620** is configured to perform an error checking and correcting process to ensure the correctness of data. To be specific, when the memory management unit **614** receives a host write command and write data corresponding to the host write command from the host system **1000** and writes the write data into the flash memory chip **606**, the error checking and correcting unit **620** generates an ECC code corresponding to the write date, and the generated error checking and correcting code is written into the physical block **122**-(**0**)~**122**-(N) with the write data. Then, when the memory management unit **614** reads data from the flash memory chip **606**, the error checking and correcting unit **620** performs the error checking and correcting process to the read data based on the ECC code corresponding to the read data. In the present exemplary embodiment, the maximum number of error correcting bits of the error checking and correcting unit **620** is 26. Namely, in a case where the number of error bits in data is not larger than 26, the error checking and correcting unit **620** is capable of detecting the error bits and correcting the data. It should be noted that the present invention is not limited thereto and the maximum number of error correcting bits of the error checking and correcting unit may be any suitable value, such as 4, 16 or 64.

In particular, after the data is written into the page of the physical block, the memory management unit **614** gives a write confirm command to the flash memory chip **606** to determine whether the write data which just is written has any error bit. To be specific, when the flash memory chip **606** receives the write confirm command, the flash memory chip **606** reads data from the physical page which just is written into; the error checking and correcting unit **620** performs the error checking and correcting process to determinate whether the read data has any error bit; and the flash memory chip **606** transmits the result of the error checking and correcting process, thereby the memory management unit **614** determinates the write data which just is written has any error bit based the result of the error checking and correcting process performed by the error checking and correcting unit **620**.

For example, during the execution of the host write command, if the error checking and correcting unit **620** determines the data read from the physical page P**2** of the physical block **122**-(D+1) has error bits and the number of error bits is larger than the maximum number of error correcting bits of the error checking and correcting unit **620** (i.e. the error checking and correcting unit **620** can not correct the error bits), the memory management unit **614** moves valid data stored in other physical pages of the physical block **122**-(D+1) to another physical block (e.g. the physical block **122**-(D+2)) and marks the physical block **122**-(D+1) as the bad physical block. And, the memory management unit **614** sends a write error message to the host system **1000**. For example, the host system **1000** may re-send the host write command and the write data corresponding to the host write command according to the write error message.

Additionally, in a case where the error checking and correcting unit **620** determines the data read from the physical page P**2** of the physical block **122**-(D+1) has error bits, if the number of error bits is not larger than the maximum number of error correcting bits of the error checking and correcting unit **620** (i.e. the error checking and correcting unit **620** can correct the error bits), the memory management unit **614** determines whether the number of error bits is larger than the error bit threshold value based on the result of the error checking and correcting process performed by the error checking and correcting unit **620**. And, if the number of error bits is larger than the error bit threshold value, the memory management unit **204** moves valid data stored in all of the physical pages of the physical block **122**-(D+1) to another physical block (e.g. the physical block **122**-(D+2)) and marks the physical block **122**-(D+1) as the bad physical block.

Furthermore, in the case where the memory management unit **614** determines the number of error bits in the data read from the physical page P**2** of the physical block **122**-(D+1) is not larger than the error bit threshold value based on the result of the error checking and correcting process performed by the error checking and correcting unit **620**, the memory management unit **614** marks the physical block **122**-(D+1) as the unreliable physical block.

It should be mentioned that the memory management unit **614** reads data which just is written from a physical block to verify whether the data is written correctly when the memory management unit **614** performs the write operation to the physical block. However, the present invention is not limited thereto, in another exemplary embodiment of the present invention, the memory management unit **614** further read data stored in other physical pages of the written physical block to determine the status of the written physical block.

FIG. **7** is a flowchart illustrating a data writing method according to the second exemplary embodiment of the present invention.

Referring to FIG. **7**, in step S**701** the flash memory controller **604** receives a host write command and a logical address and write data corresponding to the host write command from the host system **1000**.

In step S**703**, the memory management unit **614** of the flash memory controller **604** uses a data program command to write the write data into the physical page of a physical block in the flash memory chip **606** (e.g. the physical page P**2** of the physical block **122**-(D+1)) based on the logical block that the logical address belongs to.

Thereafter, in step S**705**, the memory management unit **614** gives a write confirm command to the flash memory chip **606** and receives a result of the error checking and correcting process. And, in step S**707** the memory management unit **614** determinates whether the data which just is written into the physical page (e.g. the physical page P**2** of the physical block **122**-(D+1)) has any error bit.

If in the step S**707**, it is determined the data which just is written into the physical page does not have any error bit based on the result of the error checking and correcting process, the process shown in FIG. **7** is terminated.

If in the step S**707**, it is determined that the data which just is written into the physical page has at least one error bit, in step S**709** the memory management unit **614** determines whether the number of error bits is larger than the maximum number of error correcting bits based on the result of the error checking and correcting process. And, if the number of error bits is larger than the maximum number of error correcting bits, in step S**711** the memory management unit **614** copies valid data stored in other physical pages of the physical block to another physical block (e.g. the physical block **122**-(D+2)) and in step S**713** the memory management unit **614** marks the physical block (i.e. the physical block is written in step S**703**) as the bad physical block. Thereafter, in the step S**715** the memory management unit **204** sends a write error message to the host system **1000**, and the process shown in FIG. **7** is terminated.

If the number of error bits is not larger than the maximum number of error correcting bits, in step S**717** the memory management unit **614** determines whether the number of error bits is larger than the error bit threshold value based on the result of the error checking and correcting process. If the number of error bits is larger than the error bit threshold value, in step S**719** the memory management unit **614** copies valid

data stored in all the physical pages of the physical block to another physical block (e.g. the physical block **122**-(D+2)). And, in the step S**721** the memory management unit **614** marks the physical block (i.e. the physical block is written in step S**703**) as the bad physical block, and the process shown in FIG. **7** is terminated.

If the number of error bits is not larger than the error bit threshold value, in step S**723** the memory management unit **614** marks the physical block (i.e. the physical block is written in step S**703**) as the unreliable physical block, and the process shown in FIG. **7** is terminated.

As described above, the data writing method provided by the present invention determines whether there is an error bit in data written into a flash memory, thereby the correctness of the data can effectively be ensured. Additionally, when data has at least one error bit, a physical block is marked according to an error level, thereby preventing the usage of the physical block which is unreliable and increasing the reliability of a flash memory storage system. The previously described exemplary embodiments of the present invention have the advantages aforementioned, wherein the advantages aforementioned not required in all versions of the invention.

Although the invention has been described with reference to the above embodiments, it will be apparent to one of the ordinary skill in the art that modifications to the described embodiment may be made without departing from the spirit of the invention. Accordingly, the scope of the invention will be defined by the attached claims not by the above detailed descriptions.

What is claimed is:

**1**. A data writing method for ensuring data writing correctly from a host system into a flash memory chip, wherein the flash memory chip includes a plurality of physical blocks, and each of the physical blocks has a plurality of physical pages, the data writing method comprising:

grouping the physical blocks into at least a data area, a spare area and a replacement area;

receiving a host write command and write data corresponding to the host write command from the host system and executing the host write command by the flash memory controller;

giving a data program command to the flash memory chip during the execution of the host write command to write the write data into one of the physical blocks of the spare area; and

giving a read command to the flash memory chip before sending an acknowledgement message informing that the host write command is completed to the host system to determine whether at least a portion of data stored in one of the physical pages in the one of the physical blocks corresponding to the host write command has at least one error bit,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than the maximum number of error correcting bits and is larger than an error bit threshold value, moving data stored in the one of the physical block to another physical block selected from the replacement area, and marking the one of the physical block as a bad physical block,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than an error bit threshold value, marking the one of the physical block as an unreliable physical block,

wherein the unreliable physical block is used for writing data only when the physical blocks of the replacement area are exhausted.

**2**. The data writing method according to claim **1**, wherein the flash memory controller has an error checking and correcting unit,

wherein the step of giving the read command to the flash memory chip before sending the acknowledgement message informing that the host write command is completed to the host system to determine whether the at least a portion of data stored in one of the physical pages in the one of the physical blocks has the at least one error bit comprises:

giving the read command to the flash memory chip to read data from the one of the physical blocks; and

determining whether the at least a portion of data stored in the one of the physical blocks has the at least one error bit according to the read data through the error checking and correcting unit.

**3**. The data writing method according to claim **1**, wherein the data writing method further comprises:

when the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is larger than the maximum number of error correcting bits, moving data stored in other physical pages in the one of the physical blocks having the at least one error bit to another physical block selected from the replacement area, and marking the one of the physical blocks as a bad physical block.

**4**. The data writing method according to claim **1**, further comprising:

sending a write error message to the host system by the flash memory controller when the at least a portion of data in the one of the physical blocks has the at least one error bit and is corresponding to the host write command.

**5**. The data writing method according to claim **1**, further comprising:

using an unreliable physical block table to record the unreliable physical block.

**6**. A flash memory controller for ensuring data writing correctly from a host system into a flash memory chip, wherein the flash memory chip includes a plurality of physical blocks, and each of the physical blocks has a plurality of physical pages, the flash memory controller comprising:

a microprocessor unit;

a flash memory interface unit, coupled to the microprocessor unit, and configured to connect to the flash memory chip;

a host interface unit, coupled to the microprocessor unit and configured to receive a host write command and write data corresponding to the host write command from the host system; and

a physical memory management unit, coupled to the microprocessor unit and configured to group the physical blocks into at least a data area, a spare area and a replacement area,

wherein the physical memory management unit gives a data program command to the flash memory chip during execution of the host write command to write the write data into one of the physical blocks of the spare area,

wherein the physical memory management unit gives a read command to the flash memory chip before sending an acknowledgement message informing that the host write command is completed to the host system to determine whether at least a portion of data stored in one of

the physical pages in the one of the physical blocks corresponding to the host write command has at least one error bit,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than the maximum number of error correcting bits and is larger than an error bit threshold value, the physical memory management unit moves data stored in the one of the physical blocks to another physical block selected from the replacement area and marks the one of the physical blocks as a bad physical block,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than an error bit threshold value, the physical memory management unit marks the one of the physical blocks as an unreliable physical block,

wherein the physical memory management unit uses the unreliable physical block for writing data only when the physical blocks of the replacement area are exhausted.

**7**. The flash memory controller according to claim **6**, further comprising an error checking and correcting unit,

wherein the physical memory management unit gives the read command to the flash memory chip to read data from the one of the physical blocks, and the error checking and correcting unit determines whether the at least a portion of data stored in the one of the physical blocks has the at least one error bit according to the read data during the execution of the host write command.

**8**. The flash memory controller according to claim **6**, and

wherein when the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is larger than the maximum number of error correcting bits, the physical memory management unit moves data stored in the other physical pages in the one of the physical blocks having the at least one error bit to another physical block among the physical blocks and marks the one of the physical block as a bad physical block.

**9**. The flash memory controller according to claim **6**, wherein when the at least a portion of data in the one of the physical blocks has the at least one error bit and is corresponding to the host write command, the physical memory management unit sends a write error message to the host system.

**10**. A flash memory storage system for ensuring data writing correctly, comprising:

a flash memory chip having a plurality of physical blocks, wherein each of the physical blocks has a plurality of physical pages;

a connector, configured to connect to a host system and to receive a host write command and write data corresponding to the host write command from the host system; and

a flash memory controller, coupled to the flash memory chip and the connector, and configured to group the physical blocks into at least a data area, a spare area and a replacement area,

wherein the flash memory controller gives a data program command to the flash memory chip during execution of the host write command to write the write data into one of the physical blocks of the spare area,

wherein the flash memory controller gives a read command to the flash memory chip before sending an acknowledgement message informing that the host write command is completed to the host system to determine whether at least a portion of data stored in one of the physical pages in the one of the physical blocks corresponding to the host write command has at least one error bit,

wherein if at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than the maximum number of error correcting bits and is larger than an error bit threshold value, the flash memory controller moves data stored in the one of the physical blocks to another physical block selected from the replacement area and marks the one of the physical blocks as a bad physical block,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than an error bit threshold value, the flash memory controller marks the one of the physical blocks as an unreliable physical block,

wherein the flash memory controller uses the unreliable physical block for writing data only when the physical blocks of the replacement area are exhausted.

**11**. The flash memory storage system according to claim **10**, wherein the flash memory controller has an error checking and correcting unit,

wherein the flash memory controller gives the read command to the flash memory chip to read data from the one of the physical blocks, and the error checking and correcting unit determines whether the at least a portion of data stored in the one of the physical blocks has the at least one error bit according to the read data during the execution of the host write command.

**12**. The flash memory storage system according to claim **10**, and

wherein when the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is larger than the maximum number of error correcting bits, the flash memory controller moves data stored in other physical pages in the one of the physical blocks having the at least one error bit to another physical block among the physical blocks and marks the one of the physical blocks as a bad physical block.

**13**. The flash memory storage system according to claim **10**, wherein when the at least a portion of data in the one of the physical blocks has the at least one error bit and is corresponding to the host write command, the flash memory controller sends a write error message to the host system by the flash memory controller.

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the physical pages in the one of the physical blocks corresponding to the host write command has at least one error bit,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than the maximum number of error correcting bits and is larger than an error bit threshold value, the physical memory management unit moves data stored in the one of the physical blocks to another physical block selected from the replacement area and marks the one of the physical blocks as a bad physical block,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than an error bit threshold value, the physical memory management unit marks the one of the physical blocks as an unreliable physical block,

wherein the physical memory management unit uses the unreliable physical block for writing data only when the physical blocks of the replacement area are exhausted.

**7**. The flash memory controller according to claim **6**, further comprising an error checking and correcting unit,

wherein the physical memory management unit gives the read command to the flash memory chip to read data from the one of the physical blocks, and the error checking and correcting unit determines whether the at least a portion of data stored in the one of the physical blocks has the at least one error bit according to the read data during the execution of the host write command.

**8**. The flash memory controller according to claim **6**, and

wherein when the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is larger than the maximum number of error correcting bits, the physical memory management unit moves data stored in the other physical pages in the one of the physical blocks having the at least one error bit to another physical block among the physical blocks and marks the one of the physical block as a bad physical block.

**9**. The flash memory controller according to claim **6**, wherein when the at least a portion of data in the one of the physical blocks has the at least one error bit and is corresponding to the host write command, the physical memory management unit sends a write error message to the host system.

**10**. A flash memory storage system for ensuring data writing correctly, comprising:

a flash memory chip having a plurality of physical blocks, wherein each of the physical blocks has a plurality of physical pages;

a connector, configured to connect to a host system and to receive a host write command and write data corresponding to the host write command from the host system; and

a flash memory controller, coupled to the flash memory chip and the connector, and configured to group the physical blocks into at least a data area, a spare area and a replacement area,

wherein the flash memory controller gives a data program command to the flash memory chip during execution of the host write command to write the write data into one of the physical blocks of the spare area,

wherein the flash memory controller gives a read command to the flash memory chip before sending an acknowledgement message informing that the host write command is completed to the host system to determine whether at least a portion of data stored in one of the physical pages in the one of the physical blocks corresponding to the host write command has at least one error bit,

wherein if at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than the maximum number of error correcting bits and is larger than an error bit threshold value, the flash memory controller moves data stored in the one of the physical blocks to another physical block selected from the replacement area and marks the one of the physical blocks as a bad physical block,

wherein if the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is not larger than an error bit threshold value, the flash memory controller marks the one of the physical blocks as an unreliable physical block,

wherein the flash memory controller uses the unreliable physical block for writing data only when the physical blocks of the replacement area are exhausted.

**11**. The flash memory storage system according to claim **10**, wherein the flash memory controller has an error checking and correcting unit,

wherein the flash memory controller gives the read command to the flash memory chip to read data from the one of the physical blocks, and the error checking and correcting unit determines whether the at least a portion of data stored in the one of the physical blocks has the at least one error bit according to the read data during the execution of the host write command.

**12**. The flash memory storage system according to claim **10**, and

wherein when the at least a portion of data stored in the one of the physical pages in the one of the physical blocks has the at least one error bit and the number of the at least one error bit is larger than the maximum number of error correcting bits, the flash memory controller moves data stored in other physical pages in the one of the physical blocks having the at least one error bit to another physical block among the physical blocks and marks the one of the physical blocks as a bad physical block.

**13**. The flash memory storage system according to claim **10**, wherein when the at least a portion of data in the one of the physical blocks has the at least one error bit and is corresponding to the host write command, the flash memory controller sends a write error message to the host system by the flash memory controller.

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